# **BRS212 series**

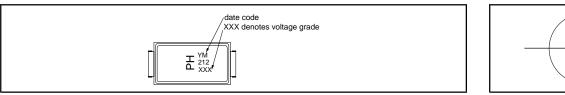
#### **GENERAL DESCRIPTION**

A range of bidirectional, breakover diodes in a two terminal, surface mounting, plastic envelope. These devices feature controlled breakover voltage and high holding current together with high peak current handling capability. Their intended application is protection of line based telecommunications equipment against voltage transients.

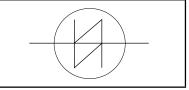
#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNIT
V <sub>(BO)</sub> I <sub>H</sub> I <sub>PP</sub>	Breakover voltage BRS212-140 BRS212-160 BRS212-180 BRS212-200 BRS212-220 BRS212-220 BRS212-240 BRS212-260 BRS212-280 Holding current Non-repetitive peak pulse current (CCITT K17)	- - - - - - - - - - - - - - - - - - -	140 160 180 200 220 240 260 280 -	- - - - - - - 40	>>>>>>> mA

#### OUTLINE - SOD106



#### SYMBOL



#### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>D</sub>	Continuous voltage	BRS212-140	-	105	V
D	3	BRS212-160	-	120	V
		BRS212-180	-	135	V
		BRS212-200	-	150	V
		BRS212-220	-	165	V
		BRS212-240	-	180	l v
		BRS212-260	-	195	V
		BRS212-280	-	210	V
I <sub>PP</sub>	Non-repetitive peak pulse	5/310 µs impulse equivalent to	-	40	A
гг	current	10/700 μs, 1.6 kV voltage impulse		-	
		(CCITT K17)			
I <sub>TSM</sub>	Non repetitive surge peak	half sine wave; t = 10 ms;	-	15	A
10101	on-state current	$T_i = 70$ °C prior to surge			
l <sup>2</sup> t	I <sup>2</sup> t for fusing	$t_{0} = 10 \text{ ms}^{2}$	-	1.1	A <sup>2</sup> s
dl <sub>⊤</sub> /dt	Rate of rise of on-state current	$t_{p}^{P} = 10 \mu s$	-	50	A/μs
	after $V_{(BO)}$ turn-on				l .
P <sub>tot</sub>	Continuous dissipation on	$T_{sp} = 50^{\circ}C$	-	4	W
101	infinite heatsink	э <b>р</b>			
P <sub>TM</sub>	Peak dissipation	$t_{p} = 1 \text{ ms}; T_{a} = 25^{\circ}\text{C}$	-	50	W
	Storage temperature	μ, α	- 40	150	°C
T <sub>stg</sub> T <sub>j</sub> T <sub>L</sub>	Operating junction temperature		-	150	) , , ,
T	Maximum terminal temperature	soldering time = 10 s	-	260	D° L
	for soldering				

# BRS212 series

## THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-sp</sub>	Thermal resistance junction to solder point		-	-	25	K/W
$R_{thj-a}$		pcb mounted; minimum footprint	-	100	-	K/W
Z <sub>th j-a</sub>	Thermal impedance junction to ambient	t <sub>p</sub> = 1 ms	-	2.6	-	K/W

# **ELECTRICAL CHARACTERISTICS**

 $T_i = 25$  °C unless otherwise stated

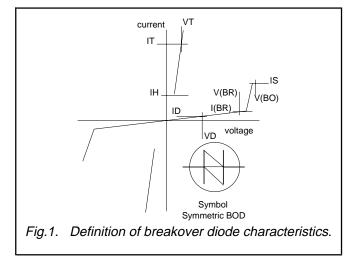
TYPE	PARAMETER								
	Marking	Avala volt			kover age	Off-state current			rate of off-state age
Conditions		I <sub>BR</sub> = 1	l0 mA	I <sub>D</sub> ≤ I <sub>S</sub> t <sub>p</sub> = 100 μs		$\begin{array}{c c} T_{j} = 70^{\circ}C; \\ RH \leq 65\% \end{array} \qquad T_{j} = 70^{\circ}C \\ \end{array}$		70°C	
Symbol		V	BR	V	BO	$I_D @ V_D$		$I_D @ V_D dV_D/dt$	
Limits		min	typ	typ	max	max		max	
Units		V	V	V	V	μA	V	V/µs	V
BRS212-140 BRS212-160 BRS212-180 BRS212-200 BRS212-220 BRS212-240 BRS212-260 BRS212-280	212-140 212-160 212-180 212-200 212-220 212-240 212-260 212-280	123 140 158 176 193 211 228 246	140 160 200 220 240 260 280	140 160 200 220 240 260 280	157 180 202 224 247 269 292 314	10 10 10 10 10 10 10	105 120 135 150 165 180 195 210	2000 2000 2000 2000 2000 2000 2000 200	105 120 135 150 165 180 195 210

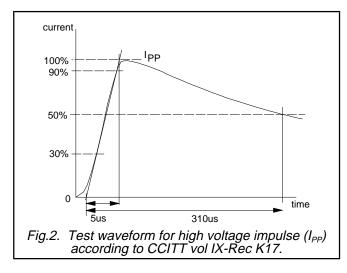
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>T</sub>	On-state voltage	$I_{TM} = 2 \text{ A}; t_p = 200 \ \mu \text{s}$	-	-	2.5	V
I <sub>H</sub>	Holding current <sup>1</sup>	$ T_i = 25^{\circ}C$	150	-	-	mĄ
	<b>a</b>	$T_i = 70^{\circ}C$	100	-	-	mA
I <sub>s</sub>	Switching current <sup>2</sup>	$t_{p} = 100 \ \mu s$	10	200	1000	mA
Š <sub>(BR)</sub>	Temperature coefficient of		-	+0.1	-	%/K
C <sub>j</sub>	avalanche voltage Junction capacitance	$V_{\rm D} = 0$ V, f = 1 kHz to 1 MHz	-	-	100	pF

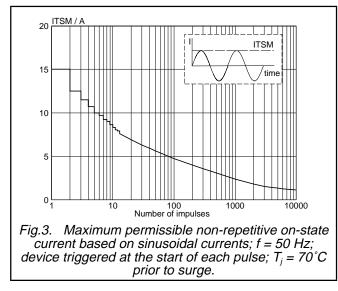
<sup>1</sup> The minimum current at which the diode will remain in the on-state

<sup>2</sup> The avalanche current required to switch the diode to the on-state.

# BRS212 series







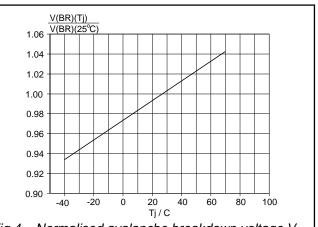
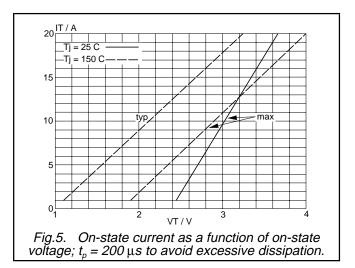
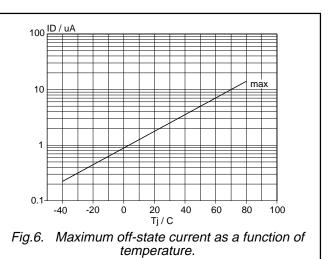
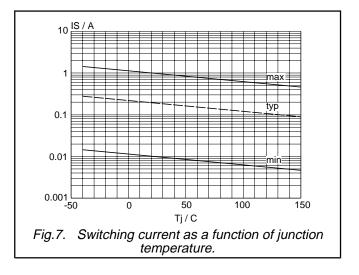


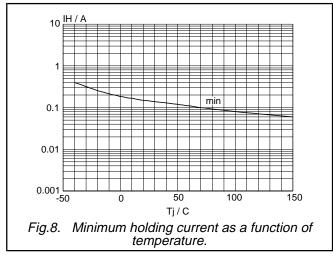
Fig.4. Normalised avalanche breakdown voltage  $V_{(BR)}$ and  $V_{(BO)}$  as a function of temperature.





# BRS212 series





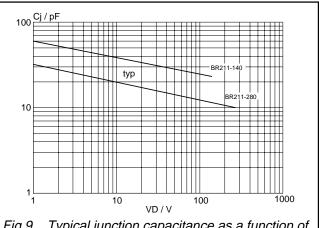
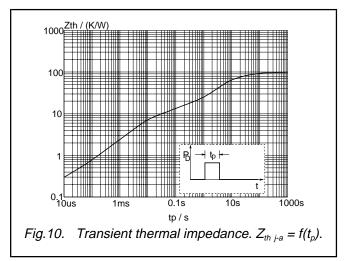


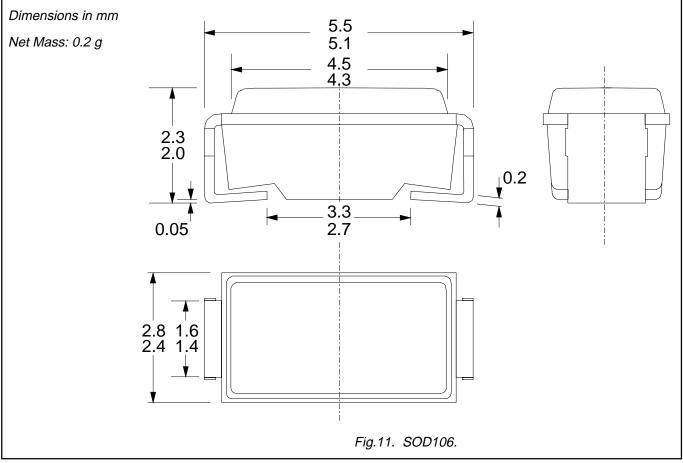
Fig.9. Typical junction capacitance as a function of off-state voltage, f = 1 MHz;  $T_j = 25 \degree C$ .



#### Product specification

# BRS212 series

### **MECHANICAL DATA**



Notes

1. For mounting and soldering instructions refer to publication SC18 "SMD Footprint Design and Soldering Guidelines". Order code:9397 750 00505.

# BRS212 series

### DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
or more of the limiting val operation of the device at	in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one lues may cause permanent damage to the device. These are stress ratings only and t these or at any other conditions above those given in the Characteristics sections of nplied. Exposure to limiting values for extended periods may affect device reliability.
Application information	l
Where application inform	ation is given, it is advisory and does not form part of the specification.
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